TOSHIBA Fast Recovery Diode Silicon Diffused Type

CMF02

Switching Mode Power Supply Applications DC/DC Converter Applications

- Repetitive peak reverse voltage: V_{RRM} = 600 V
- Average forward current: $I_F(AV) = 1.0 A$
- Forward voltage: $V_{FM} = 2.0 V (max)$
- Very fast reverse-recovery time: $t_{rr} = 100 \text{ ns} \text{ (max.)}$
- Suitable for compact assembly due to small surface-mount package "M-FLATTM" (Toshiba package name)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}	600	V
Average forward current	I _{F (AV)}	1.0 (Note 1)	А
Peak one-cycle surge forward current (non-repetitive)	IFSM	10 (50 Hz) (Note 3)	А
Junction temperature	Tj	-40~150	°C
Storage temperature range	T _{stg}	-40~150	°C

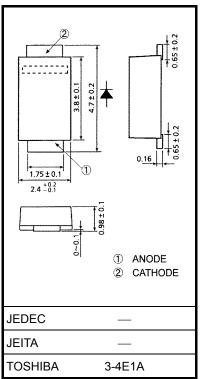
Note 1: $T\ell = 108^{\circ}C$

Rectangular waveform ($\alpha = 180^{\circ}$)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 3: This rating specifies the non-repetitive peak current in one cycle of a 50 Hz sine wave, condition angle 180°. Therefore the rating applies only to abnormal operation, which seldom occurs during the lifespan of a device.



Weight: 0.023 g (typ.)

Unit: mm

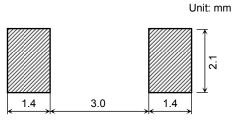
Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Peak forward voltage	V _{FM}	I _{FM} = 1.0 A (pulse test)		_	2.0	V	
Repetitive peak reverse current	I _{RRM}	V _{RRM} = 600 V (pulse test)	_	_	50	μA	
Reverse recovery time	trr	$I_{\rm F}$ = 1 A, di/dt =-30 A/ μ s	_	_	100	ns	
Forward recovery time	tfr	I _F = 1 A	_	270		ns	
Thermal resistance		Device mounted on a ceramic board (board size: 50 mm × 50 mm) (soldering land: 2 mm × 2 mm) (board thickness: 0.64 t)	_	_	60	60	
	R _{th} (j-a)	Device mounted on a glass-epoxy board (board size: 50 mm × 50 mm) (soldering land: 6 mm × 6 mm) (board thickness: 1.6 t)		135		°C/W	
		Device mounted on a glass-epoxy board (board size: 50 mm × 50 mm) (soldering land: 2.1 mm × 1.4 mm) (board thickness: 1.6 t)		_	210		
Thermal resistance (junction to lead)	R _{th (j-l)}	—	_	—	16	°C/W	

Marking

Abbreviation Code	Part No.		
F2	CMF02		

Standard Soldering Pad

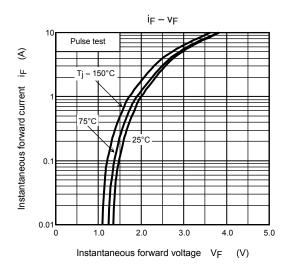


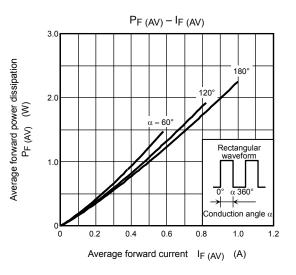
Handling Precautions

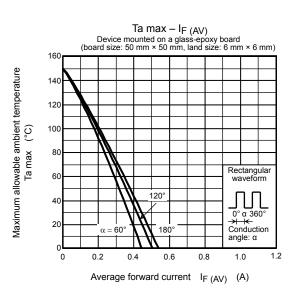
Thermal resistance between junction and ambient fluctuates depending on the mounting condition of the device. When using the device, be sure to design the circuit board and soldering land size to match the appropriate thermal resistance value.

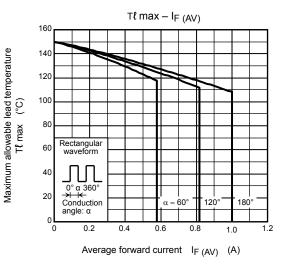
Refer to the Rectifier databook for further information.

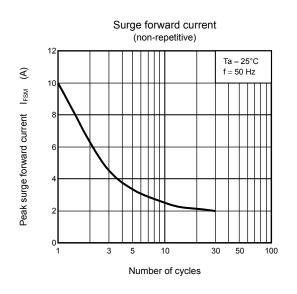
TOSHIBA

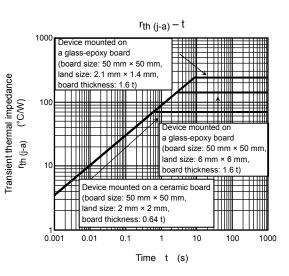












RESTRICTIONS ON PRODUCT USE

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In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.

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